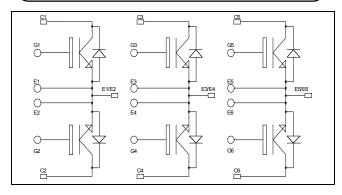


Triple Dual Common Source Trench + Field Stop IGBT3 Power Module



E3/E4

€4€4

€5/E6

$$V_{CES} = 600V$$

 $I_{C} = 50A$ @ $Tc = 80$ °C

Application

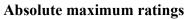
- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration



- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a dual common source configuration of three times the current capability
- RoHS Compliant



Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	80	
I_{C}	Continuous Collector Current $\frac{T_{C}}{T_{C}}$	$T_C = 80$ °C	50	Α
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	100	
$ m V_{GE}$	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	176	W
RBSOA	Reverse Bias Safe Operating Area	$T_{J} = 150^{\circ}C$	100A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.5	1.9	W
		$I_{\rm C} = 50 \text{A} \qquad \qquad T_{\rm j} = 150^{\circ} \text{C}$	$T_{j} = 150^{\circ}C$		1.7		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 600 \mu A$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
C_{ies}	Input Capacitance	$V_{GE} = 0V$			3150		
Coes	Output Capacitance	$V_{CE} = 25V$ $f = 1MHz$			200		pF
Cres	Reverse Transfer Capacitance				95		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			110		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			45		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 50A$ $R_{\text{G}} = 8.2\Omega$			200		ns
$T_{\rm f}$	Fall Time				40		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_{C} = 50A$ $R_{G} = 8.2\Omega$			120		ns
$T_{\rm r}$	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				250		
T_{f}	Fall Time				60		
Б	E _{on} Turn-on Switching Energy	$V_{GE} = \pm 15V$	$T_j = 25^{\circ}C$		0.3		mJ
Lon		$V_{\text{Bus}} = 300\text{V}$	$T_{\rm j} = 150^{\circ}{\rm C}$		0.43		1113
E_{off}	Turn-off Switching Energy	$I_{\rm C} = 50A$	$T_j = 25^{\circ}C$		1.35		mJ
∟off	Turn-on Switching Ellergy	$R_G = 8.2\Omega$ $T_j = 150^{\circ}C$		1.75		1113	

Reverse diode ratings and characteristics

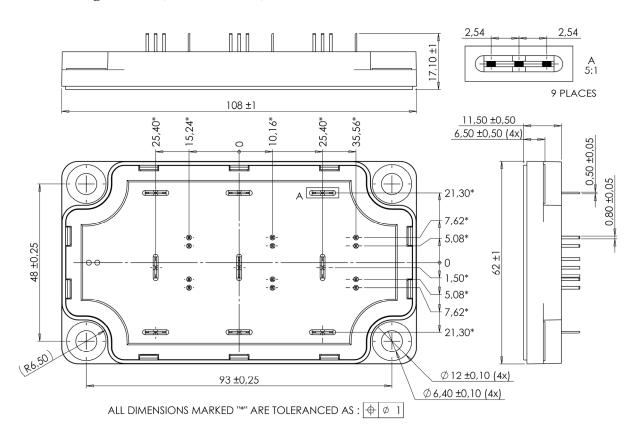
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25^{\circ}C$			250	۸
1 _{RM}			$T_j = 150$ °C			500	μA
I_F	DC Forward Current		$Tc = 80^{\circ}C$		50		A
V_{F}	Diode Forward Voltage	$I_F = 50A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.6	2	V
v F			$T_{i} = 150^{\circ}C$		1.5		
t _{rr}	Reverse Recovery Time	$I_F = 50A$ $V_R = 300V$ $di/dt = 1800A/\mu s$	$T_j = 25^{\circ}C$		100		ns μC
ι _{rr}			$T_{j} = 150^{\circ}C$		150		
Q _{rr}	Reverse Recovery Charge		$T_j = 25$ °C		2.6		
			$T_{j} = 150^{\circ}C$		5.4		μС
E_{r}	Reverse Recovery Energy		$T_j = 25^{\circ}C$		0.6		mJ
			$T_j = 150$ °C		1.2		1113



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.85	°C/W
			Diode			1.42	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_J	Operating junction temperature range			-40		175	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

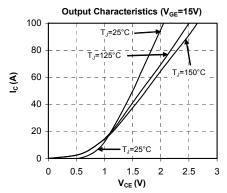
SP6-P Package outline (dimensions in mm)

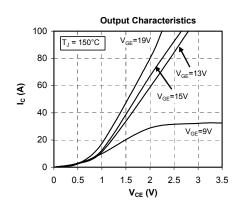


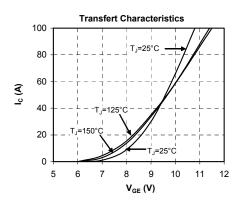
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

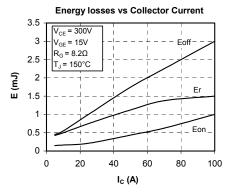


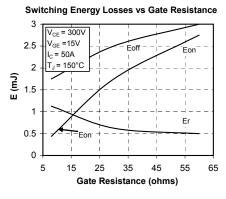
Typical Performance Curve

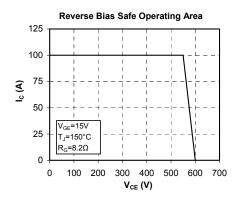


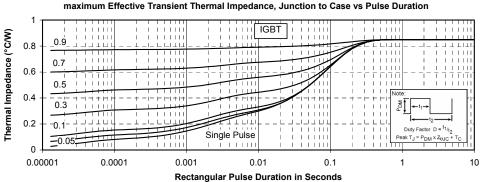




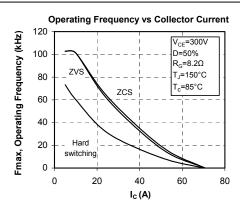


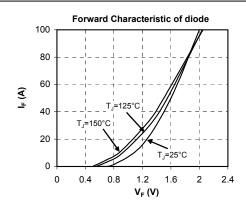


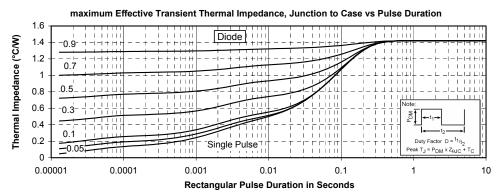














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